



# Carbon vacancy regulated photoreduction of NO to N<sub>2</sub> over ultrathin g-C<sub>3</sub>N<sub>4</sub> nanosheets



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## ARTICLE INFO

### Article history:

Received 22 May 2017

Received in revised form 19 June 2017

Accepted 4 July 2017

Available online 5 July 2017

### Keywords:

Graphitic carbon nitride

NO removal

Photoreduction

Carbon vacancy

## ABSTRACT

Photocatalytic oxidation has recently been recognized as an attractive technology for NO removal, in which the main products are NO<sub>2</sub> or HNO<sub>3</sub>. However, these products may cause secondary pollution and deactivation of the involved photocatalysts. In this study, we demonstrate that carbon vacancy-modified nanosheet structure g-C<sub>3</sub>N<sub>4</sub> (Ns-g-C<sub>3</sub>N<sub>4</sub>) can efficiently and selectively reduce NO to N<sub>2</sub> under visible light. Since N<sub>2</sub> is a green gas and can easily desorb from the active sites, the problems such as secondary pollution and catalyst deactivation are largely avoided. It was found that two structural characters of Ns-g-C<sub>3</sub>N<sub>4</sub>, ultrathin nanostructure and abundant surface defect sites, could promote its visible light absorption, and favor the separation and transfer of photogenerated charge carriers as well as strong chemisorption of NO, leading to high photoreactivity. Meanwhile, the surface defects of Ns-g-C<sub>3</sub>N<sub>4</sub> shift the adsorption structure of NO from C–N–O for the bulk counterpart to Cv–O–N (adsorbed at the carbon vacancy site, Cv), eventually resulting in its high selectivity of converting NO to N<sub>2</sub>. The present study underlines the impetus of utilizing surface defect structure to regulate photocatalytic reaction pathway.

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## 1. Introduction

Nitric oxide (NO) is one of the most common and dangerous gaseous pollutants which can cause environmental problems, such as haze, photochemical smog, and acid rain [1–3]. A major source of NO is through combustion, and since the increase of automobiles and industrial activities, the concentration of NO in the atmosphere has greatly increased over the past few decades [4,5]. Therefore, it is necessary to develop efficient, low cost and green technologies to remove NO from the atmosphere. Conventional NO removal methods include chemical adsorption, physical adsorption and thermal catalytic reduction [6–9]. However, most of these methods suffer from the problems of low efficiency, deactivation of catalyst, and secondary pollution. Semiconductor photocatalysis has recently been recognized as an attractive alternative technology for NO removal due to its high catalytic performance at moderate conditions and the abundant solar energy available [10]. In photocatalysis, light irradiation causes the bandgap excitation, producing electrons (e<sup>−</sup>) and holes (h<sup>+</sup>) located at valence and conduction band, respectively, which can then migrate to the surface

and trigger subsequent redox reactions [11]. Through the redox reaction, NO can be eliminated effectively. It was reported that TiO<sub>2</sub>, ZnO<sub>2</sub>, and Fe<sub>2</sub>O<sub>3</sub> could act as efficient photocatalysts for removing NO under UV light irradiation [12–14]. However, their intrinsic wide band gap nature makes these photocatalysts only active in UV region, which occupies only ~5% of sunlight. Therefore, it is essential to develop photocatalysts that are responsive to visible light (accounting for about 43% of sunlight). Many visible light-driven photocatalysts including (BiO)<sub>2</sub>CO<sub>3</sub>, BiOBr, Bi<sub>2</sub>MoO<sub>6</sub>, InVO<sub>4</sub> and graphitic carbon nitride (g-C<sub>3</sub>N<sub>4</sub>) have been developed and utilized for NO removal [15–20]. Among these materials, g-C<sub>3</sub>N<sub>4</sub> has attracted increasing attention because of its stability, low cost, suitable band gap of 2.7 eV and surface flexibility for chemical modification [21]. We found that g-C<sub>3</sub>N<sub>4</sub> could oxidize NO to NO<sub>2</sub> under visible light irradiation in our previous work [22]. However, NO<sub>2</sub> is an undesired product as it is more toxic than NO. Very recently, we demonstrated that the photooxidation product NO<sub>2</sub> could be further oxidized to NO<sub>3</sub><sup>−</sup> by modifying g-C<sub>3</sub>N<sub>4</sub> with Pd nanoparticles. Unfortunately, NO<sub>3</sub><sup>−</sup> will occupy the active sites and cause the catalytic deactivation of g-C<sub>3</sub>N<sub>4</sub> [23]. Therefore, it is of the utmost urgency but a challenge to design a route to remove NO without secondary pollution and catalytic deactivation.

Aside from NO<sub>2</sub> and NO<sub>3</sub><sup>−</sup>, N<sub>2</sub> is also a possible product in the photocatalytic removal of NO. Since N<sub>2</sub> is a clean gas and can easily desorb from the active sites, the problems of deactivation

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and secondary pollution can be largely avoided [24]. However, the conversion from NO to N<sub>2</sub> is very difficult because of high dissociation energy of N≡O triple bond (632 kJ/mol). Although it has been reported that TiO<sub>2</sub> can reduce NO to N<sub>2</sub> under UV light irradiation, the conversion efficiency is only 2% [24]. According to previous reports, chemical adsorption is critical to the reduction of gas molecules, such as O<sub>2</sub>, CO<sub>2</sub> and N<sub>2</sub> [25–27]. It has been shown that the chemisorption mode of the gas molecules on the surface of catalyst can control either reaction path or the reaction products [25–28]. In general, chemisorption mode of gas molecules on a catalytic material depends on its surface structure [25–28]. This is due to the fact that different surface structures may have different atom terminations and surface energies. Thus, to alter the products of photocatalytic NO removal, the catalyst's surface structure would be an important factor to control.

Recent experimental studies have shown that two dimensional nanosheet materials possess unique surface structure, giving rise to enhanced photocatalytic performance compared to their bulk counterparts [29,30]. It is reasonable to consider that nanosheet structure of g-C<sub>3</sub>N<sub>4</sub> may exhibit different behavior in photocatalytic NO conversion process than the bulk structured one. However, to the best of our knowledge, there lacks systematic study on the photocatalytic NO removal by nanosheet structured g-C<sub>3</sub>N<sub>4</sub> under visible light. In this study, we report on a simple method of synthesizing ultrathin nanosheets of g-C<sub>3</sub>N<sub>4</sub> and the application as photocatalyst for converting NO to N<sub>2</sub>, for which the detailed structure of g-C<sub>3</sub>N<sub>4</sub> nanosheet and photocatalytic mechanism were extensively investigated.

## 2. Experimental section

### 2.1. Preparation of catalysts

All chemicals used in this study were analytical-grade reagents without further purification. Nanosheet structure graphitic carbon nitride (Ns-g-C<sub>3</sub>N<sub>4</sub>) was synthesized by mixing melamine (1 g) with cyanuric acid (2 g) in 20 mL of ethanol with stirring at 333 K to remove the ethanol. The resultant mixture was put into an alumina crucible with a cover and then heated to 550 °C for 4 h in air to obtain the final samples. The bulk graphitic carbon nitride (g-C<sub>3</sub>N<sub>4</sub>) was prepared by heating melamine (3 g) in 20 mL of ethanol using the same heating procedures as just described.

### 2.2. Sample characterization

The crystal structures of the final samples were analyzed by Bruker D8 Advance X-ray diffractometer (XRD) with Cu Kα radiation at 40 kV and 40 mA. The morphology of the final samples was analyzed by transmission electron microscopy (TEM, JEOL JSM-2010). Surface electronic states were analyzed by X-ray photoelectron spectroscopy (XPS, Perkin-Elmer PHI 5000C, Al KR). All of the XPS spectra were calibrated to the C 1s peak at 284.6 eV of the surface adventitious carbon. Electron paramagnetic resonance (EPR) signals were recorded at room temperature (298 K) with a Bruker ESR A300 spectrometer. The UV–vis diffuse reflectance spectra (DRS) were obtained using a UV–vis spectrometer (Shimadzu UV-2550) by using BaSO<sub>4</sub> as a reference and were converted from reflection to absorbance by the Kubelka-Munk method. Photoluminescence spectra (PL) of the final samples were obtained using a fluorescence spectrometer (Hitachi F-4500) at 293 K. The nitrogen adsorption and desorption isotherms at 77 K were measured using Micrometrics ASAP2020 system after samples were vacuum dried at 180 °C overnight. Fourier transform infra red spectroscopy (FT-IR) spectra were obtained using a FT-IR spectrophotometer (Nicolet iS50, Thermo) with KBr as the reference sample.

### 2.3. Photocatalytic activity measurement

The experiments of photocatalytic NO removal on g-C<sub>3</sub>N<sub>4</sub> and Ns-g-C<sub>3</sub>N<sub>4</sub> were carried out in a continuous flow reactor. In the experiment, 50 mg of g-C<sub>3</sub>N<sub>4</sub> or Ns-g-C<sub>3</sub>N<sub>4</sub> was added to 10 mL of H<sub>2</sub>O and ultrasonicated for 15 min. The aqueous suspension was then cast onto the glass dish (R = 3 cm), followed by drying at 60 °C until the water was completely removed. The glass dish was placed in the middle of the reactor. A 300 W Xe lamp with a 420 nm cut-off filter was vertically placed above the quartz window, so that the incident light can irradiate directly on the sample dish. Compressed NO (10 ppm, balance with Ar) was used as the NO source. NO concentration was diluted to about 600 ppb by air stream. The flow rate was controlled at 1 L/min by a mass flow controller. The change in NO concentration was continuously measured by using a chemiluminescence NO analyzer (Thermo Scientific, 42i).

NO removal efficiency (η) was calculated as follows:

$$\eta(\%) = (1 - [\text{NO}]_f / [\text{NO}]_i) \times 100\%$$

where [NO]<sub>f</sub> and [NO]<sub>i</sub> are the concentrations of NO in the outlet stream and feeding stream, respectively.

### 2.4. Anaerobic photocatalytic NO removal

In the anaerobic photocatalytic NO removal, a 0.1 g amount of photocatalyst was uniformly dispersed on a glass reactor with an area of 4.2 cm<sup>2</sup>. The volume of the reaction system was about 230 mL. The reaction setup was vacuum-treated several times, and then 1500 ppb NO (balance with Ar) was introduced into the reaction to achieve ambient pressure. During the irradiation, about 1 mL of gas was taken from the reaction cell at given intervals for subsequent N<sub>2</sub> concentration analysis with a gas chromatograph (GC-14B, Shimadzu Corp., Japan).

The selectivity of N<sub>2</sub> (S<sub>N2</sub>) was calculated as follows:

$$S_{\text{N}_2} = ([\text{N}_2] / [\text{N}_2] + [\text{NO}_2]) \times 100\%$$

### 2.5. Electrochemical and photoelectrochemical experiments

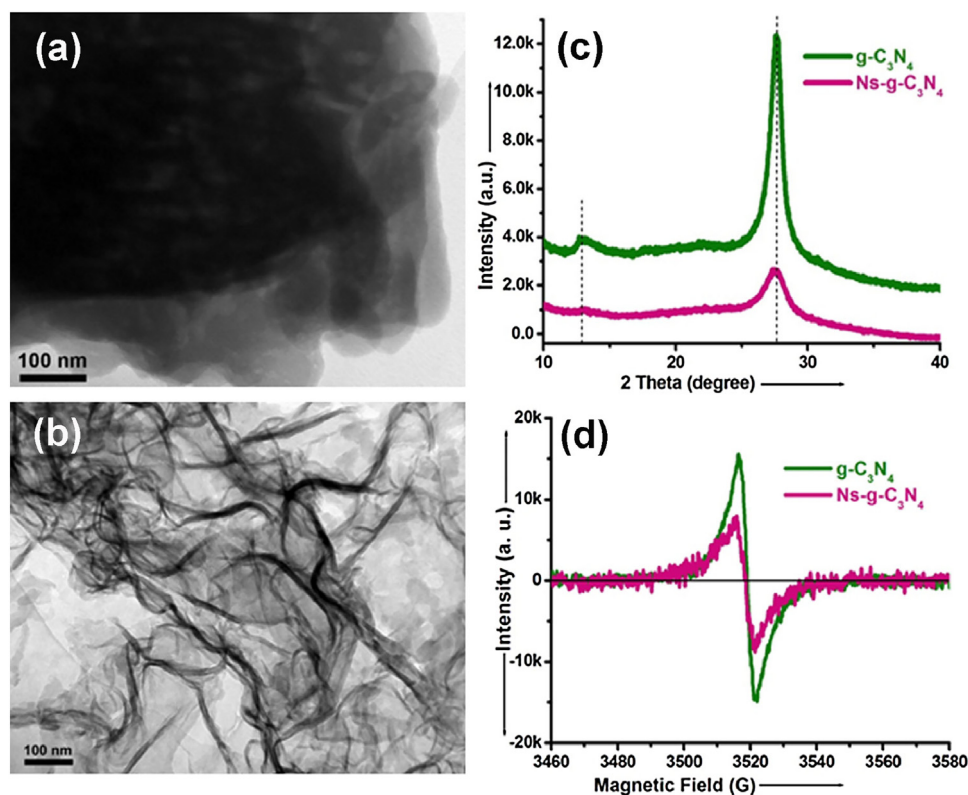
Electrochemical and photoelectrochemical measurements were performed in a three-electrode cell with a platinum plate (1 × 1 cm<sup>2</sup>) as the auxiliary electrode and a saturated calomel electrode (SCE) as the reference electrode on a CHI 660C workstation. The working electrode (photoelectrode) was immersed in a 0.1 M KCl aqueous solution. Time dependent photocurrent curves were measured with amperometric i-t curve method. A 300 W Xe lamp with a 420 nm cutoff filter was chosen as a visible light source. Nyquist plots were obtained by using the AC impedance method.

The photoelectrodes were prepared as described in our previous report [31]. Typically, the aqueous slurries of g-C<sub>3</sub>N<sub>4</sub> and Ns-g-C<sub>3</sub>N<sub>4</sub> were spin-coated on ITO glass substrate at a spin rate of 3000 rpm for 30 s under low vacuum. The films on ITO glass substrate were dried in air and annealed at 200 °C for 1 h as the final photoelectrodes.

## 3. Results and discussion

### 3.1. Structure characterization for samples

The microstructures of the result samples were investigated by transmission electron microscopy (TEM). Fig. 1a shows that the bulk g-C<sub>3</sub>N<sub>4</sub> sample synthesized with only melamine is of a multi-layer structure. Alternatively, when the mixture of melamine and cyanuric acid was used as precursor, the resulting Ns-g-C<sub>3</sub>N<sub>4</sub> sample was composed of ultrathin nanosheets with a thickness of 10 nm



**Fig. 1.** TEM image of g-C<sub>3</sub>N<sub>4</sub> (a) and Ns-g-C<sub>3</sub>N<sub>4</sub> (b). XRD patterns of g-C<sub>3</sub>N<sub>4</sub> and Ns-g-C<sub>3</sub>N<sub>4</sub> (c). EPR patterns of g-C<sub>3</sub>N<sub>4</sub> and Ns-g-C<sub>3</sub>N<sub>4</sub> (d).

(Fig. 1b). The crystal structures of the two samples were compared by X-ray diffraction (XRD) measurements (Fig. 1c). Both the two samples contain two peaks at about 13.0° and 27.4°, matching well with the (100) and (002) crystal planes of g-C<sub>3</sub>N<sub>4</sub>, respectively. No other impurity peaks can be detected in the XRD pattern of Ns-g-C<sub>3</sub>N<sub>4</sub>, indicating that the co-calcination with cyanuric acid does not affect the crystal structure of the graphite-like carbon nitride. However, the peak at 27.4° of Ns-g-C<sub>3</sub>N<sub>4</sub> is weaker, suggesting that the interlayer structure of g-C<sub>3</sub>N<sub>4</sub> has been weakened, which agrees well with the change in the micro-morphology. Previous work suggested that nanosheets may contain additional surface defect sites compared to their bulk counterparts [29]. It is therefore reasonable to speculate that the surface of Ns-g-C<sub>3</sub>N<sub>4</sub> prepared in this study also contain such defects. To test this hypothesis, electron paramagnetic resonance (EPR) spectrometry was used to detect the presence of defects. Fig. 1d shows that the bulk g-C<sub>3</sub>N<sub>4</sub> exhibits a Lorentzian line originating from the unpaired electrons on the carbon atoms of the aromatic rings [26]. In Ns-g-C<sub>3</sub>N<sub>4</sub>, this line is considerably damped, which signifies a reduction in the number of unpaired electrons, likely due to the formation of carbon vacancies.

To understand this proposed defect formation, X-ray photoelectron spectroscopy (XPS) was employed to investigate the surface chemical composition and chemical states of the two g-C<sub>3</sub>N<sub>4</sub> samples. High-resolution XPS peaks of C 1s of the two samples can be deconvoluted into two peaks, which are ascribed to the carbon in C–N<sub>3</sub> (288.2 eV) and C–C (284.6 eV), arising from the adventitious carbon) groups, respectively (Fig. 2a). The area ratios of the two peaks at 288.2 and 284.6 eV are calculated to be 2.7 and 1.6 for g-C<sub>3</sub>N<sub>4</sub> and Ns-g-C<sub>3</sub>N<sub>4</sub>, respectively. This decrease in area ratio suggests that the tertiary carbon content in Ns-g-C<sub>3</sub>N<sub>4</sub> is decreased, which in turn suggests an increase in carbon vacancies. Moreover, the high-resolution XPS peaks of N 1s of g-C<sub>3</sub>N<sub>4</sub> can be fitted with two peaks, which are ascribed to the C–N–C (398.4 eV) and C–N<sub>3</sub> (400.7 eV) groups, respectively. However, in addition to these two

peaks, a new peak, which is attributed to the amino groups (–NH<sub>2</sub>, 401.3 eV), was observed in the high-resolution XPS spectra of Ns-g-C<sub>3</sub>N<sub>4</sub> (Fig. 2b). The formation of amino groups is in consistency with the decrease in tertiary carbons, further implying the formation of carbon vacancies.

### 3.2. Photocatalytic NO removal

The photocatalytic activities of the two g-C<sub>3</sub>N<sub>4</sub> samples were examined for the NO removal preformed in a continuous flow reactor system. Inlet NO concentrations were 600 ppb flowing at a constant rate of 1 L/min. Experimental details can be found in the supporting information. Control experiments showed that there was no observable NO removal in the absence of either the photocatalyst or visible light irradiation (Fig. 3a), indicating that both the photocatalyst and visible light are necessary for the present photocatalytic NO removal. Fig. 3a shows that 38% of NO could be removed over bulk g-C<sub>3</sub>N<sub>4</sub> under visible light irradiation (>420 nm) for 40 min. In comparison, Ns-g-C<sub>3</sub>N<sub>4</sub> shows significantly improved photocatalytic activity with 48% of NO removed in only 30 min under the same visible light irradiation. The NO concentration change follows first-order kinetics, and the NO removal rate over Ns-g-C<sub>3</sub>N<sub>4</sub> is 5 times of that over g-C<sub>3</sub>N<sub>4</sub> (Fig. 3b). Since the removal of NO can be either through a reduction pathway to N<sub>2</sub>, or an oxidation way to NO<sub>2</sub>, we first studied the reaction process by monitoring the production of NO<sub>2</sub>, as well as the concentration change. For the bulk g-C<sub>3</sub>N<sub>4</sub>, a large amount of NO<sub>2</sub> was produced (with yield percentage of 80%) after 30 min of visible light irradiation, suggesting that the major photocatalytic product in this case was NO<sub>2</sub> (Fig. 3c). However, when the ultrathin nanosheets of g-C<sub>3</sub>N<sub>4</sub> were used as the photocatalyst, the concentration of NO<sub>2</sub> generated was much lower (with yield percentage of 33%). One possibility accounting for this difference is that Ns-g-C<sub>3</sub>N<sub>4</sub> may facilitate deep oxidation of NO to NO<sub>3</sub><sup>–</sup> or NO<sub>2</sub><sup>–</sup>, decreasing the formation of NO<sub>2</sub>. Con-

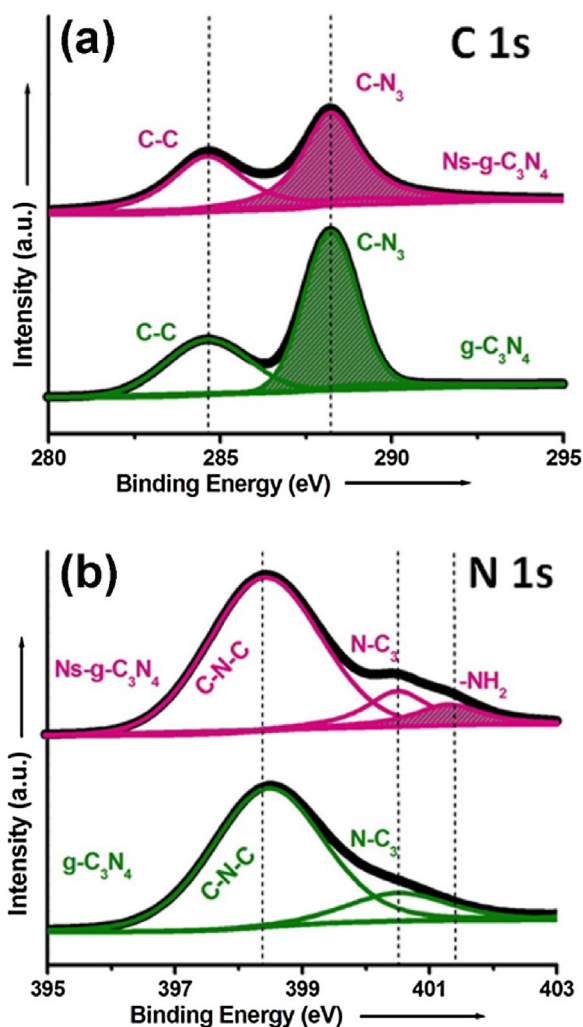


Fig. 2. High-resolution XPS spectra of C 1s (a) and N 1s (b) of  $g\text{-C}_3\text{N}_4$  and  $\text{Ns-g-C}_3\text{N}_4$ .

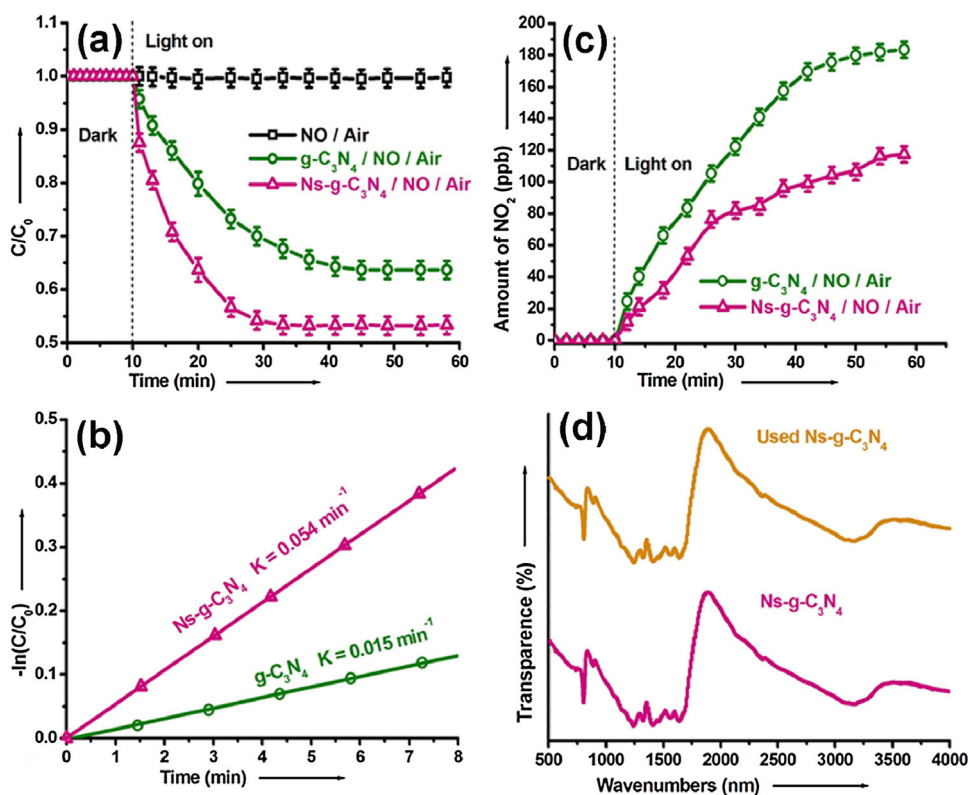
sidering the strong adsorption of  $\text{NO}_3^-$  or  $\text{NO}_2^-$  on the surface of  $g\text{-C}_3\text{N}_4$ , we should be able to detect the presence of these ions if the deep oxidation indeed occurred. However, FTIR measurement over the  $\text{Ns-g-C}_3\text{N}_4$  sample collected after the photocatalytic reaction found no peaks corresponding to  $\text{NO}_3^-$  or  $\text{NO}_2^-$  (Fig. 3d). This implied that significant amount of NO must have gone through a different reaction process over  $\text{Ns-g-C}_3\text{N}_4$ , and been converted to a different product.

In order to explore the reaction pathways in  $\text{Ns-g-C}_3\text{N}_4$  system, trapping experiments were carried out to investigate and compare photocatalytic removal of NO. When potassium iodide (KI, a hole scavenger) [32] was added into the materials, the NO removal was completely inhibited over  $g\text{-C}_3\text{N}_4$  (Fig. S1a), whereas the NO removal over  $\text{Ns-g-C}_3\text{N}_4$  was reduced by only 30%. This observation implies that photogenerated holes are indispensable for NO removal over  $g\text{-C}_3\text{N}_4$  but not for  $\text{Ns-g-C}_3\text{N}_4$ . On the other hand, with addition of potassium dichromate ( $\text{K}_2\text{Cr}_2\text{O}_7$ , an electron scavenger) [33] the NO removal was significantly depressed for both  $g\text{-C}_3\text{N}_4$  and  $\text{Ns-g-C}_3\text{N}_4$  (Fig. S1a and S1b), suggesting that the photogenerated electrons play a critical role in NO removal in both cases. In the presence of oxygen, the photogenerated electrons can form various active species participating in the catalytic response. To probe this, scavengers such as tert-butyl alcohol (TBA) for  $\cdot\text{OH}$ , p-benzoquinone (PBQ) for  $\cdot\text{O}_2^-$  and catalase (CAT) for  $\text{H}_2\text{O}_2$  were further tested on the photocatalytic response [34–36]. As shown in Figs. S1a and S1b, the addition of TBA and CAT did not change the NO

removal rate over both  $g\text{-C}_3\text{N}_4$  and  $\text{Ns-g-C}_3\text{N}_4$ . On the contrary, PBQ could depress the NO removal on both samples. Interestingly, the NO removal efficiency of both samples in the presence of PBQ was almost equal to that in the presence of KI. Thus, we conclude that both the photogenerated hole and  $\cdot\text{O}_2^-$  are indispensable, playing the synergic roles, in the NO removal over  $g\text{-C}_3\text{N}_4$ . However, the NO removal over  $\text{Ns-g-C}_3\text{N}_4$  is attributed not only to the synergic roles of hole and  $\cdot\text{O}_2^-$ , but also to other more important contributions related to the electrons.

Based on the importance of photogenerated electrons on the NO removal mechanism, as well as the unaccounted for product of NO reduction evidenced by the suppression of  $\text{NO}_2$  formation in the  $\text{Ns-g-C}_3\text{N}_4$  system, a photoreduction mechanism is proposed. It has been reported that oxygen vacancies in  $\text{TiO}_2$  lead to selective reduction of NO into  $\text{N}_2$  under UV light irradiation [24]. Similarly, in this work, the carbon vacancy within the surface of  $\text{Ns-g-C}_3\text{N}_4$  would also lead to the reduction of NO under visible light irradiation. To prove this, the compressed air carrier gas was replaced with high-purity argon gas to achieve anaerobic testing conditions. The results are shown in Fig. 4. NO removal on  $g\text{-C}_3\text{N}_4$  is completely suppressed (Fig. 4a), suggesting that molecular oxygen was involved in NO removal with  $g\text{-C}_3\text{N}_4$ . However, the NO removal in  $\text{Ns-g-C}_3\text{N}_4$  was only reduced by 34% (Fig. 4b) compared to the test in air, suggesting that oxygen is not indispensable for NO removal over  $\text{Ns-g-C}_3\text{N}_4$ . Gas chromatography (GC) measurements were carried out to identify the products of the anaerobic photocatalysis with





**Fig. 3.** (a) The relative change of NO concentration ( $C/C_0$ ) as a function of irradiation time tested over  $g-C_3N_4$  and  $Ns-g-C_3N_4$ . (b) First order kinetics fitting for the data obtained from  $g-C_3N_4$  and  $Ns-g-C_3N_4$ . (c)  $NO_2$  concentration changing with irradiation time tested over  $g-C_3N_4$  and  $Ns-g-C_3N_4$ . (d) The FTIR spectra of  $Ns-g-C_3N_4$  before and after used in photocatalytic removal of NO.

$Ns-g-C_3N_4$ , and the GC spectra measured from the outlet gas of the reaction system is shown in Fig. 5b, where the formation of  $O_2$  and  $N_2$  is clearly evidenced. The area the  $O_2$  to  $N_2$  peaks in the GC spectra shows a 1:1 ratio, different from what is measured in the air sample (Fig. 5a). The 1:1 ratio is expected for the stoichiometric reduction of NO. Alternatively, no observable  $N_2$  or  $O_2$  peaks were seen with the  $g-C_3N_4$  samples after 1 h of visible light irradiation (Fig. 5c). In addition, no  $N_2$  and  $O_2$  were detected over  $Ns-g-C_3N_4$  when the photocatalytic system was illuminated by introducing Ar instead of NO/Ar into the reactor. These observations provide strong evidence that NO was reduced into  $N_2$  and  $O_2$  over  $Ns-g-C_3N_4$ . Based on the results of Fig. 5c, the selectivity of  $N_2$  was calculated to be 66% for  $Ns-g-C_3N_4$ . To the best of our knowledge, this is the highest selectivity of  $N_2$  in photocatalytic NO removal under the visible light irradiation [24].

### 3.3. The mechanism of activity enhancement

Photocatalytic NO removal starts with absorption of light energy, which in turn generates electrons and holes, causing surface reactions with NO. The photogeneration of electrons strongly depends on the band structure of the semiconductor catalyst. UV-vis absorption spectra of  $g-C_3N_4$  and  $Ns-g-C_3N_4$  are displayed in Fig. 6. The intrinsic direct band edge of  $Ns-g-C_3N_4$  shows a slight blue shift compared with  $g-C_3N_4$  (Fig. 6a); the  $g-C_3N_4$  band gap of 2.7 eV increased to 2.8 eV for  $Ns-g-C_3N_4$  (Fig. 6b). These changes are related to the quantum confinement effect (QCE), which is caused by the exfoliation in our system. At the same time, the absorption spectrum of  $Ns-g-C_3N_4$  extends to the whole visible light region, possibly due to excitation into the lower energy defect states. In such case,  $Ns-g-C_3N_4$  would absorb more visible light than  $g-C_3N_4$ , thereby generating more charges.

The photogenerated charges may undergo two fates: one is to migrate to the surface of the photocatalyst for subsequent chemical reactions; the other is to recombine with each other. The distance between the excitation sites and the surface depends on the morphology of the semiconductors. The morphology change from multi-layer structure to ultrathin nanosheets would shorten the distance for the photogenerated electrons to reach the surface, thus facilitating the charge separation. Additionally, our previous works revealed that carbon vacancies have the ability to capture electrons and suppress the radiative recombination of the photogenerated charges [26]. Therefore, the photogenerated electrons and holes are likely separated more efficiently in  $Ns-g-C_3N_4$  than in  $g-C_3N_4$ . To test this, photoluminescence (PL) measurements were performed to study the separation of photogenerated electrons and holes in  $g-C_3N_4$  and  $Ns-g-C_3N_4$ . Fig. 6c displays the PL spectra of the two samples under 330 nm excitation at room temperature. The strong emission peak of  $g-C_3N_4$  around 455 nm was derived from the direct band transition. By contrast, the PL intensity of  $Ns-g-C_3N_4$  was more than 50% lower, indicating the higher efficiency in separation of the photogenerated charge carriers. Moreover, beside the PL peak at 455 nm intrinsic to  $g-C_3N_4$ , a new band appeared at long wavelength in the PL spectrum of  $Ns-g-C_3N_4$  sample, which may be due to radiative recombination from the shallow trapped electrons, likely at the carbon vacancies.

Electrochemical tests were performed in a three-electrode cell with a  $g-C_3N_4$  coated working electrode to further understand the dynamics of electron transfer at the  $g-C_3N_4$  surface. Fig. 6d shows the current of the electrochemical cell with pulsed light excitation. Under light illumination, both  $g-C_3N_4$  and  $Ns-g-C_3N_4$  generated significant photocurrent, implying efficient photogeneration of charge carriers in both materials that then transferred to the working electrode. Interestingly, the  $Ns-g-C_3N_4$  system showed a lower photocurrent compared to the  $g-C_3N_4$  system despite

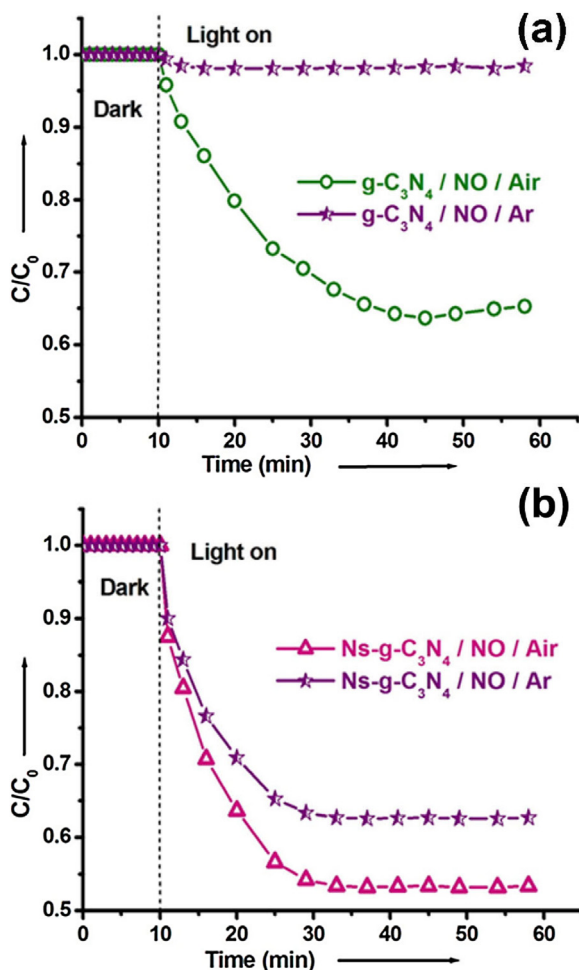


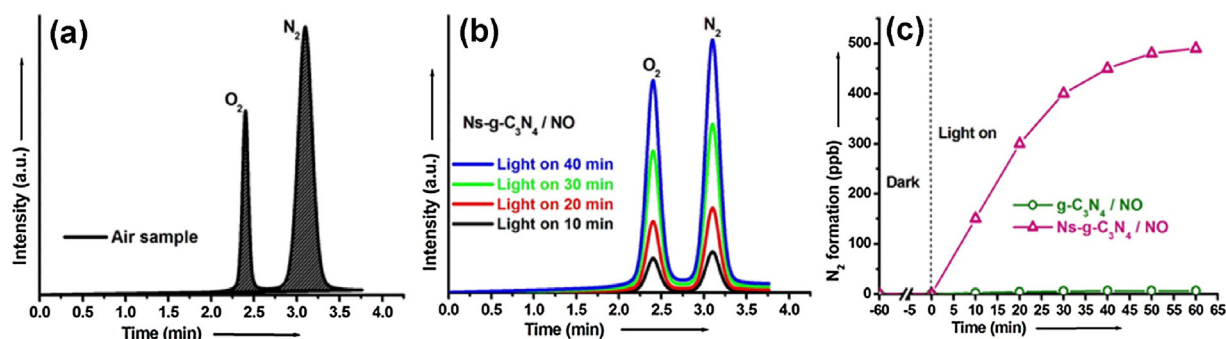
Fig. 4. Comparison of NO removal over  $g-C_3N_4$  under aerobic and anoxic condition (a); Comparison of NO removal over  $Ns-g-C_3N_4$  under aerobic and anoxic condition (b).

having larger light absorption and higher efficiency of charge separation as discussed above, which combined should result in a higher photocurrent. Therefore, it is expected that the charge transfer to the working electrode and/or the electrolyte in  $Ns-g-C_3N_4$  system is inhibited due to the surface defects of carbon vacancy. Reduction of Cr(VI) via the photocatalysis was performed to measure the charge transfer properties at the surface. Indeed  $Ns-g-C_3N_4$  exhibits lower reactivity in the photoreduction of Cr(VI), whose activity is merely 22% that of  $g-C_3N_4$  (Fig. 6e), despite the higher surface area and expected larger photogenerated carrier concentrations of  $Ns-g-C_3N_4$ . These results, in consistency with the PL measurement above, indicate that the shallow level electron trapping (likely caused by carbon vacancies) inhibits the electron transport from the surface of  $Ns-g-C_3N_4$ . This is further confirmed by the measurements of electrochemical impedance shown in Fig. 6f. The Nyquist plots of the two samples show that the semicircle in the plot of  $Ns-g-C_3N_4$  is larger than that of  $g-C_3N_4$ , indicating an increase in the charge transfer resistance on the surface. Based on all these experimental results, it can be concluded that  $Ns-g-C_3N_4$  can produce more photoelectrons than  $g-C_3N_4$ , though the electrons generated are favorably trapped at the carbon vacancy sites.

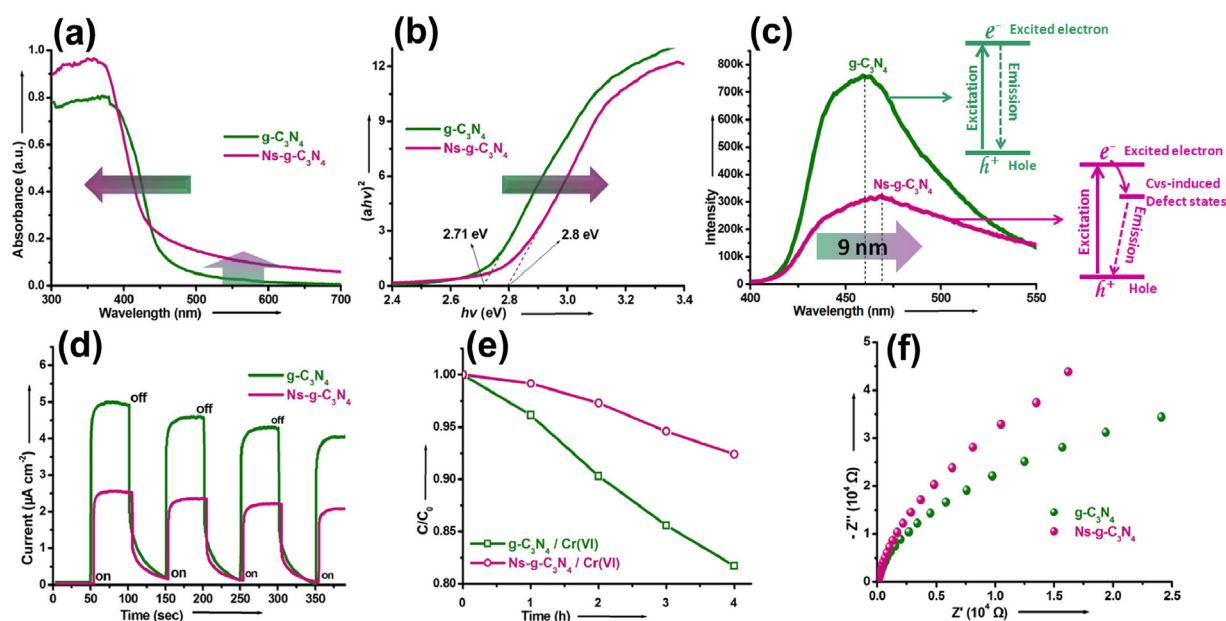
The conclusion made above that the photogenerated electrons are confined in defects does not sound consistent with the fact that  $Ns-g-C_3N_4$  exhibited higher reactivity in the photoreduction of NO to  $N_2$ . Such inconsistency can be explained by the different adsorption modes of the reactants on the surface of  $g-C_3N_4$  and  $Ns-g-C_3N_4$ , which in turn affect the reaction rate and mechanism of the photocatalysis. Herein the adsorption of NO on  $g-C_3N_4$  and  $Ns-g-C_3N_4$

was extensively investigated in order to understand the effect on the photocatalytic activity. First, temperature-programmed desorption (TPD) of NO was investigated as displayed in Fig. S2. For  $g-C_3N_4$ , a single peak at 267 °C was observed, compared to two peaks at 267 °C and 370 °C for  $Ns-g-C_3N_4$ . The common peak at 267 °C is much weaker in the  $Ns-g-C_3N_4$  sample, suggesting that the new strong adsorption mode at 370 °C is the dominant adsorption mode for NO on  $Ns-g-C_3N_4$ . This new strong adsorption mode is likely the source for the efficient photoreduction of NO on  $Ns-g-C_3N_4$ .

As previously reported, the nitrogen atom of NO has an unpaired electron, making it behave as a free radical. Meanwhile, the C atom in  $g-C_3N_4$  also has an unpaired electron (Fig. S3a). Thus, the N atom of NO can interact with the C atom in  $g-C_3N_4$  via radical coupling (Fig. S3b). Based on the results of EPR and XPS, the  $Ns-g-C_3N_4$  defects are located on the C atoms, and the original free radical property of C atom may disappear. In addition, previous studies showed that the vacancies could act as the capture centers for  $O_2$  molecules or the oxygen end of NO molecules [24,26]. As a result, the carbon vacancy of  $Ns-g-C_3N_4$  may prefer to interact with the O atom rather than N atom. To confirm this change in NO adsorption modes, EPR measurement was conducted to compare the samples before and after NO adsorption. As shown in Fig. 7a, both  $g-C_3N_4$  samples with and without NO adsorption show a sharp signal which could be assigned to the unpaired electrons on the carbon atoms in the aromatic rings. Interestingly, the signal intensity of  $g-C_3N_4$  with the NO adsorption is lower than that without the NO adsorption. This is due to the fact that N atom of NO can interact with the C atom



**Fig. 5.** The GC spectrum of air sample (a); The GC spectra of NO after the photocatalysis (b); photocatalytic conversion of NO to  $N_2$  and  $O_2$  over  $g-C_3N_4$  and  $Ns-g-C_3N_4$  (c). In anaerobic experiments, initial concentration of NO was 1500 ppb, the amount of  $g-C_3N_4$ , and  $Ns-g-C_3N_4$  used was 50 mg, a 300 W Xe lamp with a 420 nm cutoff filter was used as the visible light source.



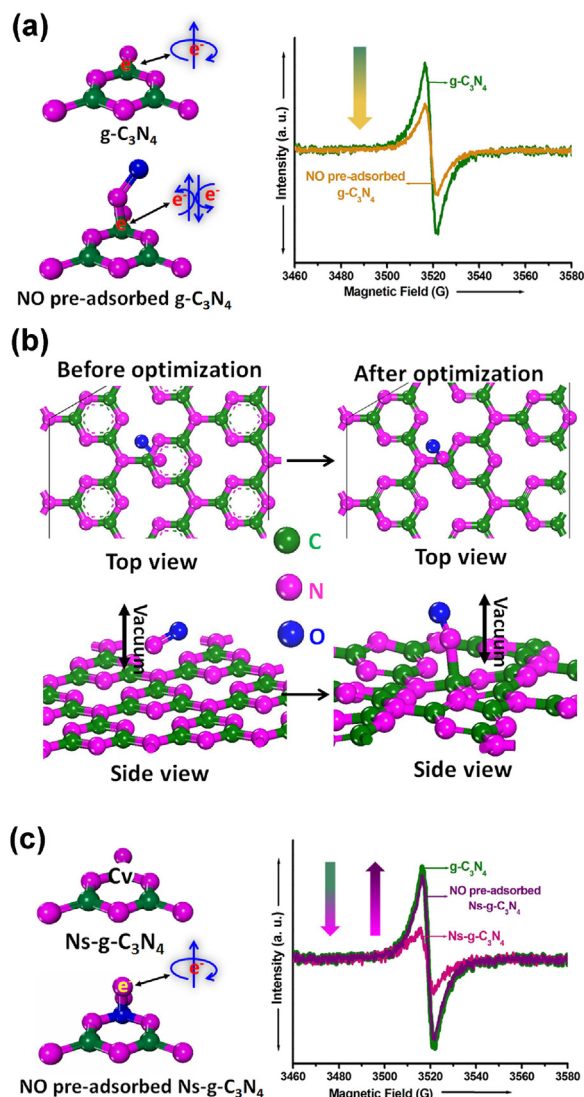
**Fig. 6.** UV-vis absorption spectra of  $g-C_3N_4$  and  $Ns-g-C_3N_4$  (a); the plots of  $(ah\nu)^2$  versus energy ( $h\nu$ ) of  $g-C_3N_4$  and  $Ns-g-C_3N_4$  (b); Photoluminescence spectrum of the  $g-C_3N_4$  and  $Ns-g-C_3N_4$  (c); The light dependent electrochemical current using  $g-C_3N_4$  and  $Ns-g-C_3N_4$  coated working electrodes (d); photoreduction of  $Cr(VI)$  over  $g-C_3N_4$  and  $Ns-g-C_3N_4$  (e); electrochemical impedance spectra of  $g-C_3N_4$  and  $Ns-g-C_3N_4$  (f).

in  $g-C_3N_4$ , thus decreasing the amount of the unpaired electrons in  $g-C_3N_4$ . The observation confirms the radical coupling mechanism of NO onto  $g-C_3N_4$  surfaces as proposed above. The radical coupling driven adsorption is also supported by density functional theory (DFT) simulations. To simulate the molecular NO adsorption on surface of  $g-C_3N_4$ , a  $3 \times 3$  supercell with a 15 Å vacuum thickness was used. Before surface energy optimization (Fig. 7b), NO molecules were located in the vacuum layer randomly. However, after the optimization, NO approaches the nearest C atom and results in  $\sigma$  bonding between N atom and C atom. This adsorption dynamic simulation is consistent with the result shown in Fig. 7a. As mentioned before, the ESR signal intensity of  $Ns-g-C_3N_4$  is lower than that of  $g-C_3N_4$  because of the increase in carbon vacancies. However, after NO pre-adsorption, its signal intensity increases to the same level as that of pristine  $g-C_3N_4$  (Fig. 7c). This ESR change of  $Ns-g-C_3N_4$  is contrary to that of  $g-C_3N_4$ , suggesting that carbon vacancy can serve as an active site to adsorb NO through interaction with the O atom of NO, leaving the radical at the N-atom, which results in an increase in the ESR signal of  $Ns-g-C_3N_4$  sample.

To further confirm that the carbon vacancies on the  $Ns-g-C_3N_4$  surface are the chemical adsorption sites for NO, these defect sites were intentionally blocked with photodeposition of Pd. Consider-

ing that photogenerated electrons are favorably confined in the defect sites, the particles of Pd can be selectively deposited on the defect sites through in situ photocatalytic reduction (Fig. 8). It is well known that NO can be adsorbed on the surface of Pd through the interaction between N atom and Pd [37]. Therefore, when the defects are blocked with Pd particles, the surface adsorption of NO will be dominated by the mode between N atom and Pd, whereas the mode based on interaction between carbon vacancy the O atom of NO will diminish, thus losing the ESR signal enhancement as observed for the pristine  $Ns-g-C_3N_4$  sample. Indeed as shown in Fig. 8, for Pd modified  $Ns-g-C_3N_4$  the NO pre-adsorption does not increase the ESR signal.

The results above reveal that the carbon vacancies on  $Ns-g-C_3N_4$  serve two roles in the photocatalytic NO reduction. First, the carbon vacancies serve as traps for the photogenerated electrons, and this was supported by the electrochemical analysis shown in Fig. 6d and e. Second, the carbon vacancies provide preferential adsorption sites for NO. The localization of both the photogenerated electron and NO molecule to the same site allows for efficient reduction of NO through direct electron transfer. This direct electron transfer is supported by the decrease in PL intensity with increasing concentration of NO in Ar carrier gas as seen in Fig. 9. In contrast,



**Fig. 7.** The effect of the pre-adsorption of NO on the EPR spectrum of  $g\text{-C}_3\text{N}_4$  and  $\text{Ns-g-C}_3\text{N}_4$ .

$g\text{-C}_3\text{N}_4$  does not exhibit any change in PL under the same conditions, confirming that there is no direct charge transfer between NO and  $g\text{-C}_3\text{N}_4$ . The direct charge transfer also explains the higher efficiency and conversion rate of NO in the  $\text{Ns-g-C}_3\text{N}_4$  system compared to the bulk  $g\text{-C}_3\text{N}_4$ .

All in all, a possible pathway of photocatalytic reduction of NO over  $\text{Ns-g-C}_3\text{N}_4$  is proposed. The first step would be the adsorption of NO on surface of  $\text{Ns-g-C}_3\text{N}_4$  through the  $\text{Cv-O-N}$  interaction. The O–N single bond of  $\text{Cv-O-N}$  is then interrupted by the photogenerated electrons, thereby releasing the decomposed N and O. The decomposed N or O atoms react with each other and form the  $\text{N}_2$  and  $\text{O}_2$ . To test this possibility, in situ ESR spectral measurement was conducted on pristine  $\text{Ns-g-C}_3\text{N}_4$  and NO pre-adsorbed  $\text{Ns-g-C}_3\text{N}_4$ . As shown in Fig. 10, both samples with and without NO pre-adsorption show a sharp signal. When  $\text{Ns-g-C}_3\text{N}_4$  sample was irradiated with visible light, the corresponding ESR signal showed an obvious increase, due to photogeneration of electrons (Fig. 10a). However, the visible light irradiation does not increase the ESR signal of NO pre-adsorbed  $\text{Ns-g-C}_3\text{N}_4$ . Additionally, the EPR peak of NO pre-adsorbed  $\text{Ns-g-C}_3\text{N}_4$  shows a shift after the irradiation with visible light, implying that the kind of defect in NO pre-adsorbed  $\text{Ns-g-C}_3\text{N}_4$  has changed. Moreover, the visible light irradiation on NO pre-adsorbed  $\text{Ns-g-C}_3\text{N}_4$  leads to the appearance of two new

ESR signals with the magnetic field of 3535 and 3555, respectively (Fig. 10b). These two signals can be attributed to the decomposed N and decomposed O [38,39]. This unambiguously proves the reduction pathway of NO over  $\text{Ns-g-C}_3\text{N}_4$  as proposed above (Fig. 10c). To investigate the stability of  $\text{Ns-g-C}_3\text{N}_4$ , we conducted a recycling test for NO removal as shown in Fig. S4. No significant change in NO removal activity was found after four cycles, confirming that the active sites are not poisoned in the NO photoreduction process. This result can also be reflected in the Gas chromatography (GC) measurements because the area of  $\text{O}_2$  to  $\text{N}_2$  peaks shows a 1:1 ratio (Fig. 5b), implying no oxygen end or nitrogen end of NO was left on the surface of  $\text{Ns-g-C}_3\text{N}_4$  after the NO removal. Moreover, the structure analysis of used  $\text{Ns-g-C}_3\text{N}_4$  was also explored. Compared with XRD, EPR and XPS of initial  $\text{Ns-g-C}_3\text{N}_4$ , no significant changes can be found in XRD, EPR and XPS of used one (Fig. S5), indicating the structure of  $\text{Ns-g-C}_3\text{N}_4$  is stable during photocatalytic NO removal.

#### 4. Conclusions

In conclusion, we successfully fabricated ultrathin  $\text{Ns-g-C}_3\text{N}_4$  nanosheets and investigated its photocatalytic properties with NO gas removal. Compared with  $g\text{-C}_3\text{N}_4$ ,  $\text{Ns-g-C}_3\text{N}_4$  exhibits higher conversion efficiency and conversion rate of NO. While  $g\text{-C}_3\text{N}_4$  results in exclusive photooxidation of NO to  $\text{NO}_2$ ,  $\text{Ns-g-C}_3\text{N}_4$  also enables photoreduction of NO to  $\text{N}_2$ . It was found that the excellent photocatalytic activity of  $\text{Ns-g-C}_3\text{N}_4$  is due to the existence of carbon vacancies at the surface compared to the bulk  $g\text{-C}_3\text{N}_4$ . These vacancy defects acted as electronic traps to localize the photogenerated electrons, while also serving as adsorption sites for NO through interface binding of  $\text{Cv-O-N}$ . The localization of both the photogenerated electron and NO molecule to the same site leads to the direct electron transfer from vacancy defect to NO, resulting in reduction of NO to  $\text{N}_2$  and  $\text{O}_2$ . The direct electron transfer also explains the higher efficiency and conversion rate of NO photoreduction on  $\text{Ns-g-C}_3\text{N}_4$  compared to that on bulk  $g\text{-C}_3\text{N}_4$ . The present work not only provides a new strategy towards achieving NO photoreduction at semiconductors, but also gives insight in molecular level understanding of the relationship between surface defect chemistry and the photocatalytic pathways of NO conversion. Lastly, to the regard of environmental impact, this work introduces an efficient and inexpensive method to remove harmful ambient NO pollution by converting it into environmentally benign  $\text{N}_2$  gas, bringing a new way to use solar energy to solve air pollution.

#### Acknowledgments

Financial support by the National Nature Science Foundation of China (Grant No. 21603271 and 21473248), NSF (CBET 1502433) and the CAS/SAFEA International Partnership Program for Creative Research Teams is gratefully appreciated.

#### Appendix A. Supplementary data

Supplementary data associated with this article can be found, in the online version, at <http://dx.doi.org/10.1016/j.apcatb.2017.07.010>.

The photoreduction of Cr(VI) in the presence of different photocatalysts under visible light; the influence of different scavengers on the photocatalytic removal of NO; NO TPD spectra of  $g\text{-C}_3\text{N}_4$  and  $\text{Ns-g-C}_3\text{N}_4$ ; Repeated testing of NO removal over  $\text{Ns-g-C}_3\text{N}_4$ .



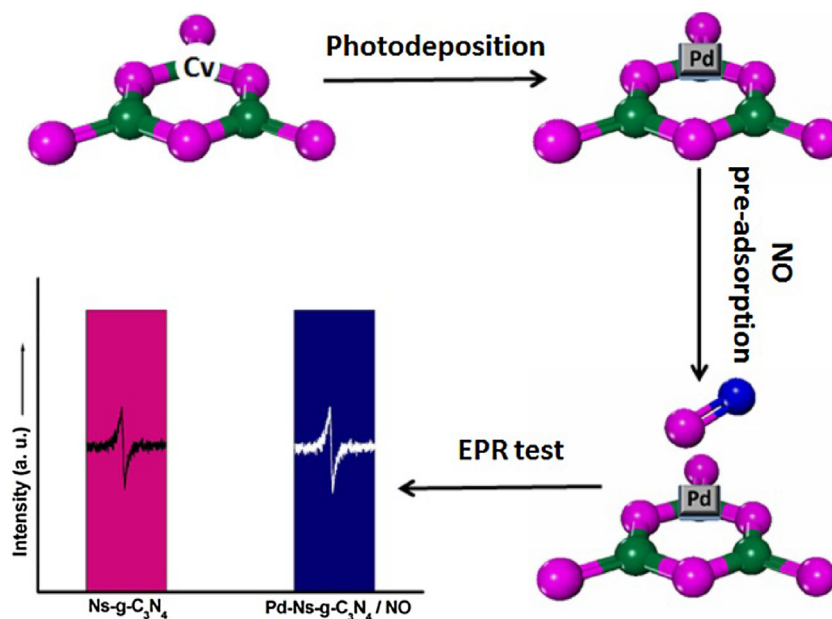


Fig. 8. The effect of the Pd on the NO adsorption on Ns-g-C<sub>3</sub>N<sub>4</sub>.

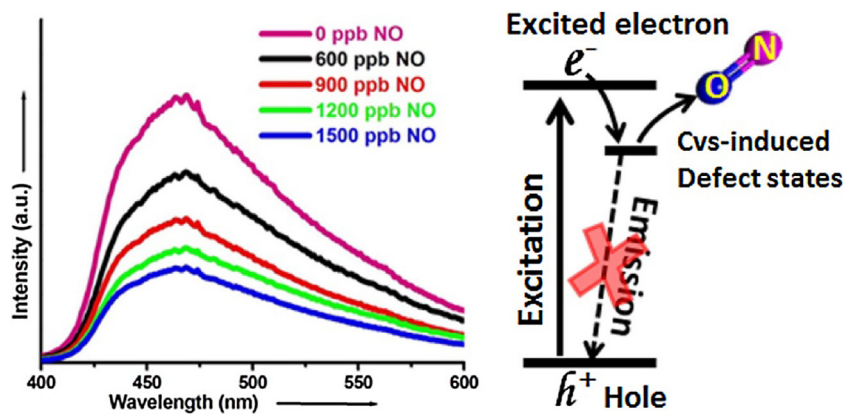


Fig. 9. The effect of the NO on the Photoluminescence spectrum of Ns-g-C<sub>3</sub>N<sub>4</sub>.

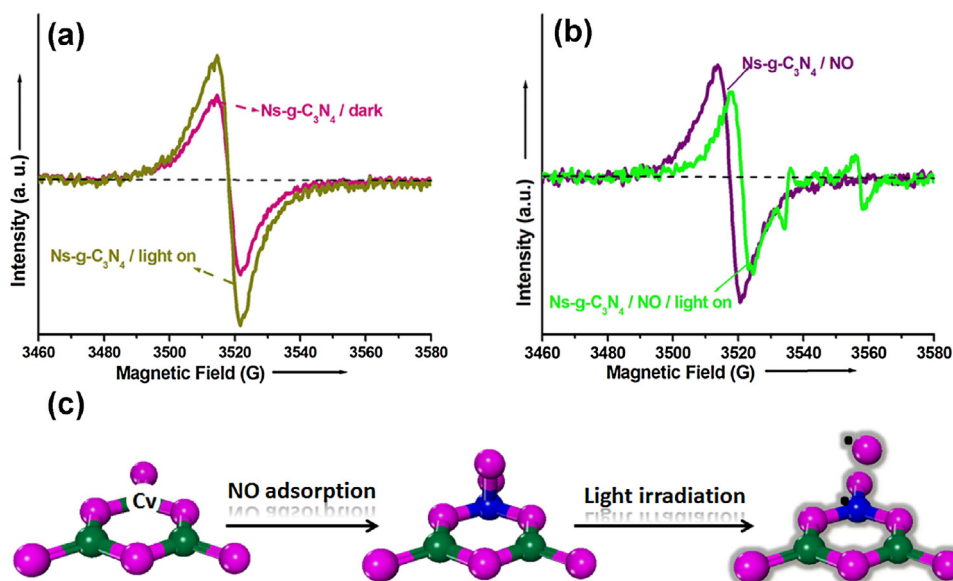


Fig. 10. The effect of the light irradiation on the EPR spectrum of Ns-g-C<sub>3</sub>N<sub>4</sub> (a) and NO pre-adsorbed Ns-g-C<sub>3</sub>N<sub>4</sub> (b); the decomposition process of NO on the surface of Ns-g-C<sub>3</sub>N<sub>4</sub> (c).

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